

IPB35N12S3L26ATMA1 Information


For Reference Only

Part Number IPB35N12S3L26ATMA1
Manufacturer Infineon Technologies
Category Discrete Semiconductor Products
 Transistors - FETs, MOSFETs - Single
Description MOSFET N-CHANNEL_100+
Package -
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


IPB35N12S3L26ATMA1 Specifications

Manufacturer Part Number	IPB35N12S3L26ATMA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	-
Series	*
FET Type	-
Technology	-
Drain to Source Voltage (Vdss)	-
Current - Continuous Drain (Id) @ 25°C	-
Drive Voltage (Max Rds On, Min Rds On)	-
Vgs(th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	-
Input Capacitance (Ciss) (Max) @ Vds	-
Vgs (Max)	-
FET Feature	-
Power Dissipation (Max)	-
Rds On (Max) @ Id, Vgs	-
Operating Temperature	-
Mounting Type	-
Supplier Device Package	-
Package / Case	-

[Report errors?](#)

IPB35N12S3L26ATMA1 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IPB35N12S3L26ATMA1 Payment Methods



IPB35N12S3L26ATMA1 Shipping Methods



If you have any question about IPB35N12S3L26ATMA1, please do not hesitate to contact us!

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